A PROGRAMMED COURSE IN

hasic transistors

NEW YORK INSTITUTE OF TECHNOLOGY

A PROGRAMMED COURSE IN BASIC TRANSISTORS

THE STAFF OF ELECTRICAL TECHNOLOGY DEPARTMENT NEW YORK INSTITUTE OF TECHNOLOGY ALEXANDER SCHURE, Project Director

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A PROGRAMMED COURSE IN BASIC TRANSISTORS

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A PROGRAMMED COURSE IN BASIC TRANSISTORS

OTHER BOOKS PREPARED BY THE STAFF OF NEW YORK INSTITUTE OF TECHNOLOGY

- A PROGRAMMED COURSE IN BASIC ELECTRICITY
- A PROGRAMMED COURSE IN BASIC ELECTRONICS

Preface

The programmed course in basic transistors contained in this book continues a tested procedure for taking firm steps toward electronic specialization. Starting with the assumption that the student has a background in the fundamentals of electricity and electronics, this course develops the basic electrical concepts related to transistors that are essential to later studies in electronics. The carefully organized logical sequence of interrelated steps permits the student to proceed at a pace best suited to his abilities and needs. He is constantly aware of his progress by means of immediate feedback as well as many checks and repetitions. He is his own tutor and his own examiner. Visual instruction is aided by clear, uncomplicated diagrams. Mathematics has been kept at a minimum, especially in the earlier sections of the work, to enable the nonmathematically minded reader to achieve a firm grasp of the necessary concepts.

There is one major prerequisite for the successful completion of this course: *interest*. An inner drive to learn is often a more important ingredient than a high I.Q. Armed with determination and perseverance, the man with a strong desire to learn simply cannot fail.

The text is designed for an introductory one-semester course; it is preceded by two additional texts, also in linear programmed form: A Programmed Course in Basic Electricity and A Programmed Course in Basic Electronics. Each may be used independently, or the three may be studied in sequence.

The three books had their beginnings in 1958. At that time, faculty members of the electrical technology department of New York Institute of Technology undertook the development of an integrated series of programmed learning materials relating to electronics. In conferences held with training directors and curriculum specialists, an agreement was reached on the topics comprising those segments of electronic training considered essential in the majority of industrial and formal educational programs. The conferees further agreed that variations in background would require structuring the programs on several levels, with one major program being fundamental in approach. The overall project was termed the PRINCE Project (Programmed Reinforced Instruction Necessary to Continuing Education). This volume is part of the series dealing with the basics of electricity, electronics, semiconductors, transistors, and pulse circuits.

By early 1961, preliminary versions of the programs had been prepared and tested by the programming teams. The next step required extensive field testing under various instructional conditions. In May of 1961, the Institute requested the assistance of the Educational Coordinating Committee of the Electronics Industries Association, offering the developed programs to industry on a cooperative data-exchange basis. Participating companies were asked to make their test data available for use in refining, revision, and developing a validated teaching instrument. Through the efforts of the committee, and through the interest of other industrial groups, a number of companies became aware of the project and agreed to aid in the validation. Among these companies were:

Aerovox Corporation, New Bedford, Massachusetts
The Boeing Company, Renton, Washington
Corning Glass Works, Corning, New York
E. I. DuPont de Nemours & Company, Wilmington, Delaware
Eastman Kodak Company, Rochester, New York
General Dynamics/Pomona, Pomona, California
General Electric Company, Philadelphia, Pennsylvania
Hycon Manufacturing Company, Monrovia, California
International Telephone and Telegraph, Belleville, New Jersey
Lockheed Aircraft Corporation, Missiles and Space Division, Sunnyvale,
California
McDonnell Aircraft Corporation, Saint Louis, Missouri

Concurrent with the industrial validation, a validation program in a number of technical institutes and community colleges was undertaken with the cooperation of McGraw-Hill, Inc. Thus, all material was thoroughly tested in the preliminary version titled *Basic Transistors*.

The data gathered from these exchanges were returned to the programming teams as the study progressed. Revisions were then made and the restructured programs retested and put in final form.

Grateful acknowledgment is hereby extended to the General Electric Company for its permission to reproduce illustrations and curves from the 6th edition of the General Electric Transistor Manual for this programmed work; to Benjamin Edelman of Western Electric, Chairman of the Educational Coordinating Committee of the Electronics Industry Association; George Maedel of RCA, Chairman of the Curriculum Development Task Force of EIA during the major portion of this study; the training directors of the participating companies; the programming teams and faculty of New York Institute of Technology; and the many others who, through their efforts, brought this project to fruition.

ALEXANDER SCHURE

To the User

Programmed instruction

No matter how deeply you probe the nature of electronics, you will always be dealing with certain basic principles. The understanding necessary to become an electronics technician comes from a grasp of the fundamental concepts of electricity.

As your skill in electronics grows, you will realize how important these basic ideas are. To understand the complex, you should know about the simple. Much of this basic information is in the program which follows.

The information in this course is organized in a relatively new manner. As you work with the materials in the lessons that follow, you will find that the information you are asked to learn has been arranged to provide for your participation in the instruction. This method of teaching is called programmed learning.

In presenting the information, the subject matter is divided into small units called frames. Most of the time, each frame requires that the statement in the frame be completed. With a little thought you should be able to provide the correct answer, or response. The correct answer is enclosed in parentheses and appears at the beginning of the frame which follows. You should look at the correct answer only after you have written what you feel to be the proper one.

In order to introduce you to this method, the following section is programmed. Cover the answers with a cardboard or paper sheet. Lower the sheet only *after* you have written your answer. Use reasonable judgment to decide whether your response is the same as the printed answer. Now try the sample frames which follow.

| 1. Self-instructional materials will be given to you in the same form as the frames which follow. Your first feelings may be that you are taking a test. You are not! Understand this clearly—programmed learning is a teaching method and is much more than just a t (Complete the statement.) | |
|---|--|
| 2. (test) The purpose of this book is to teach you in just the same way as if you were receiving individual instruction. So, your self-instructional text, called a program, acts as your private teacher. We can now say: A self-instructional book is called a p | |

| 3. (program) A program presents the information to be learned in small bits, a few sentences at a time. You will either complete a statement, find information on a diagram, or make a choice. For example, you might be asked to complete this statement: What you learn from each frame of this program will not be graded because the program is a (test, teaching device). |
|---|
| 4. (teaching device) Let's move on now. We've said the program presents information in small amounts at a time. These small segments are called frames. Each numbered statement in the program is a frame. This is the fourth in this series. |
| 5. (frame) Thus, we see each frame leads us further into the subject by giving a little additional information or by searching for information learned in that frame or a previous one. After receiving this information, you check the next frame to determine, immediately, if you are |
| 5. (correct) |
| Information Panel Some frames or chapter introductions give you information and do not ask you to make a response. Information and summaries given in this way are important. Read them carefully. Then, just go on to the next frame. Do so now. |
| 6. Let's summarize: Programmed learning involves breaking up the subject matter into small units, called |
| 7. (frames) Each frame will require a(n) from you. |
| 8. (response <i>or</i> answer) In the frame below, you will find the correct |
| 9. (response or answer) From time to time you will be given supplementary material in the form of problems and exercises. You will be required to do these and |
| ····· |

| One of the great advantages of programmed material is that each student can proceed at his own |
|--|
| 11. (rate or pace) Because you are working at your own rate, there will be no limit for your completion of "daily lessons." |
| 12. (time) Remember the difference between the words teach and learn. The program will teach, but only you, the, can learn. |
| 13. (student) You must, therefore, make the effort to from the program. |
| 14. (learn) No matter how a course is taught, the responsibility for learning is with you, the |
| 15. (student) The program is a teaching device and not a Since this is so, there is no reason to look ahead for an answer. If you do so, you will merely be cheating yourself of the opportunity of leing. |
| 16. (test, learning) Extra learning steps are built into the program. Completion summaries and check quizzes will help you ——————————————————————————————————— |
| 17. (learn) You are to complete each of these self tests. Be sure to answer every question. You may then compare your answer with the answer shown. |
| 18. (correct) Remember, when you reach the ction summaries, you are to fill them in and check your answers. You are also required to answer all the questions in the quizzes. |
| 18. (completion, check) |

You are now ready to proceed with the program.

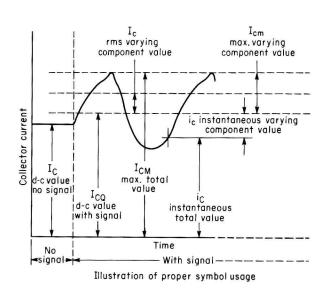
Voltage, Current, and Power Symbols (IEEE Standards)

| ELECTRICAL QUANTITIES | EXAMPLES |
|--|--------------------|
| BASE LETTERS: | |
| Instantaneous values, which vary with time, are represented by lowercase letters | i, v, p |
| Average (d-c) and RMS values are represented by capital letters | I, V, P |
| SUBSCRIPTS: | |
| D-c and instantaneous total values are indicated by capital-letter subscripts | i_E, I_E, V_{CB} |
| Varying component values are indicated by lowercase subscripts | i_e, I_e, v_{eb} |
| SUBSCRIPT REFERENCE: | |
| Base electrode | B, b |
| Collector electrode | C, c |
| Emitter electrode | E, e |

SYMBOLS

| SUBSCRIPTS | i, v, p | I, V, P |
|-------------|--|--|
| b c e | Instantaneous varying component value | RMS or effective varying component value |
| В С Е | Instantaneous total value | Average (d-c) value |

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xiv

Contents

PREFACE v

TO THE USER xi

CHAPTER 1 • SEMICONDUCTOR FUNDAMENTALS 1

Introduction
Matter and Its Structure
Atomic Structure
Conductors, Insulators, and Semiconductors
Introduction to Crystals
Impurities
Properties of Holes
Holes as Current Carriers
PN Junction Barrier
PN Junction Bias
Diode Action

CHAPTER 2 • TRANSISTOR FUNDAMENTALS 36

Introduction to Transistors
Currents in a PNP Transistor
Currents in an NPN Transistor
Input and Output Circuits
How a Transistor Amplifies
Comparison of Transistors and Electron Tubes
Designations and Symbols
Transistor Configurations
Single-battery Transistor Circuits
Phase Relationships in a CB Amplifier
Phase Relationships in a CE Amplifier
Phase Relationships in a CC Amplifier
Magnitude and Direction of Base Current
Medial Summary

CHAPTER 3 • PARAMETERS, EQUIVALENT CIRCUITS, AND CHARACTERISTIC CURVES 79

General Information—Equivalent Circuits
Dependent and Independent Variables
Constant Voltage and Constant Current Sources
Input Circuit Equation
The Output Equation
Static Characteristic Curves Applied to the Input Circuit
Static Characteristic Curves Applied to Output Circuit
Review of Input and Output Factors
Development of the Equivalent Circuit

CHAPTER 4 • PARAMETER CALCULATIONS 112

The Current-gain Equation
Typical Circuit for Numerical Evaluation of Current Gain
The Voltage-gain Equation
Numerical Evaluation of Voltage Gain
The Power-gain Equation and Numerical Example
Input and Output Resistances
CB and CC Conversions
Other Common Parameter Symbols

CHAPTER 5 • BIAS STABILIZATION 132

Stability of Operating Point
Importance of Emitter-base Junction Resistance
General Bias Circuit
Current Stability Factor
Resistor Bias Methods and Voltage Stability
Thermistor Stabilizing Circuits
Diode Stabilizing Circuits
Transistor Stabilized Circuits
The Zener Diode
Shunt Limiting Action of a Diode

CHAPTER 6 • USING CHARACTERISTIC CURVES AND CHARTS 178

Output Curves and Calculation of Gains
Dynamic Transfer Characteristic
Constant Power Dissipation Line
Interelement Capacitances
Comparison of Configurations with Respect to Resistances
Comparison of Configurations with Respect to Gain

CHAPTER 7 • AUDIO AMPLIFIERS I 200

Preamplifier Principles
Direct-coupled Preamplifiers with Frequency Compensation
Coupling Networks
Volume and Tone Controls
One-stage Phase Inverter Drivers
Two-stage Phase Inverters

CHAPTER 8 • AUDIO AMPLIFIERS II 238

Power Amplifiers—Part 1
Power Amplifiers—Part 2
Principles of Complementary Symmetry
Complementary Symmetry Circuits
Compound-connected Transistors
Two-transistor Bridge Connection
Other Bridge Arrangements

CHAPTER 9 • TUNED AMPLIFIERS 269

Review of Resonant Circuits
Transformer Coupling, Tuned Primary
Capacitance Coupling
Double-tuned Networks
Unilateralized Common-base Amplifier
Unilateralization of Common-emitter Amplifier
Automatic Gain Control Theory
Typical Tuned Amplifier

CHAPTER 10 • WIDEBAND AMPLIFIERS 308

Review of Recurrent Waveforms
Behavior of Wideband Amplifiers
The Meaning and Cause of Phase Distortion
Frequency Compensation in Wideband Transistor Amplifiers

CHAPTER 11 • OSCILLATORS (LC TYPE) 332

Introduction
Analysis of Basic Oscillator Circuit
Standard Transistor Oscillators

CHAPTER 12 • TRANSISTOR CONSTRUCTION METHODS 347

Purification of Transistor Metal Junction-forming Techniques The Alloy Transistor Rate-grown and Grown-diffused Transistors Mesa and Planar Transistors

CHAPTER 13 • READING TRANSISTOR SPECIFICATIONS 366

Absolute Maximum Ratings Small-signal Characteristics High-frequency and D-C Characteristics

CHAPTER 14 • TRANSISTOR MEASUREMENTS 378

Reverse Diode Characteristics
Measurement of Some Major Electrical Characteristics
The Measurement of Power Gain
Analysis of a Low-cost Transistor "Checker"

COMPLETION SUMMARIES AND CHECK QUIZZES 403

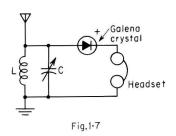
ANSWERS TO COMPLETION SUMMARIES AND CHECK QUIZZES 456

INDEX 471

CHAPTER 1 Semiconductor Fundamentals

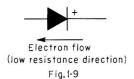
| Introduction | | | |
|--|--|--|--|
| 1.1 A triode vacuum tube is a "valve" in which the flow of electrons is controlled by voltages between grid and cathode. A transistor is also a "valve" in the same sense as a triode. In the transistor, the flow of and other "current carriers" is also controlled. | | | |
| 1.2 (electrons) A triode depends upon the flow of current carriers (electrons) through a near vacuum inside the tube envelope. In a transistor, the flow of current carriers occurs in a material known as a "semiconductor" rather than in a as in the triode. | | | |
| 1.3 (vacuum) The transistor's ability to control carriers makes it potentially the most useful single element in modern signal communications and entertainment equipment. | | | |
| 1 • 4 (current) In increasing numbers, are being applied in military radio, sound, radar, facsimile, telephone, teletypewriter, and computer assemblies. | | | |
| 1.5 (transistors) The first semiconductor "crystals" to be used in radio appeared in early receivers where they were used to recover the audio-frequency component from a received carrier. Thus, the first use for semiconductor crystals was that of demodulation or of an AM signal. | | | |
| 1.6 (detection or rectification, etc.) In these early "crystal sets," the semiconductor material was usually lead sulfide or galena. A galena-metal interface has the property of high resistance for one direction of current flow and low resistance for the other. Thus, a galena crystal can be used to perform the function of since it changes a-c to pulsating d-c. | | | |

1.7 (rectification or detection, etc.) A simple crystal set circuit is shown (Fig. 1.7). The required resonant assembly is formed by the combination of L and ______.



1.8 (C) The station to be heard is selected by adjusting the variable capacitor C. Detection or rectification is then accomplished by use of the ______ crystal, and reproduction of the audio is handled by the headset.

1.9 (galena) A semiconductor crystal rectifier is universally symbolized as shown (Fig. 1.9). The triangular element bears no identifying marks, but the "flat-plate" element here is identified by a ______ sign; such a sign is not always included.



1•10 ("+") The symbol is always used as shown to indicate the direction of conductivity for electrons. Electrons flow easily in the direction of the arrow. Thus, electrons flow easily from the flat-plate element toward the _______ element.

1.11 (triangular) The reason for the "+" designation used on the flat-plate element can be seen from Fig. 1.11. In this circuit, a(n) ______ generator is shown in a circuit containing a crystal rectifier and a load.

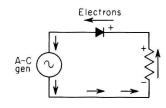


Fig.1-11

1.12 (a-c) The direction of ______ flow is shown by the arrows; we might call this the direction of electron conductivity.

1.13 (electron) It is seen that the flat-plate element is at the same potential as the *positive* end of the load resistor. Hence, the flat plate is labeled ______.

1.14 ("+") During World War II, efficient semiconductor rectifiers were widely used (Fig. 1.14). By this time, galena had been abandoned as a semiconductor and was replaced by a better material. As shown in Fig. 1.14, this new semiconductor material is called ________.

